



10A, 50V - 1000V High Efficient Rectifier

FEATURES

- AEC-Q101 qualified available
- High efficiency, low V_F
- High current capability
- High surge current capability
- Low power loss
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

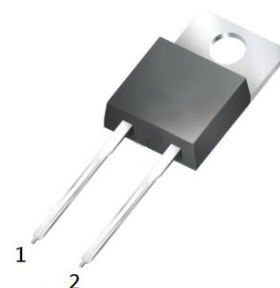
APPLICATIONS

- DC to DC converters
- Switching mode converters and inverters
- Freewheeling application

MECHANICAL DATA

- Case: TO-220
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.82g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I_F	10	A
V_{RRM}	50 - 1000	V
I_{FSM}	125	A
$T_{J\ MAX}$	150	°C
Package	TO-220	
Configuration	Dual dies	



TO-220

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)										
PARAMETER	SYMBOL	HER 1001G	HER 1002G	HER 1003G	HER 1004G	HER 1005G	HER 1006G	HER 1007G	HER 1008G	UNIT
Marking code on the device		HER 1001G	HER 1002G	HER 1003G	HER 1004G	HER 1005G	HER 1006G	HER 1007G	HER 1008G	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V
Forward current	I_F	10								A
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I_{FSM}	125								A
Junction temperature	T_J	-55 to +150								°C
Storage temperature	T_{STG}	-55 to +150								°C



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-case thermal resistance	$R_{\theta JC}$	1.5	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage per diode ⁽¹⁾	HER1001G	$I_F = 5\text{A}, T_J = 25^\circ\text{C}$	V_F	-	1.0	V
	HER1002G			-	1.3	V
	HER1003G			-	1.7	V
	HER1004G			-	1.7	V
	HER1005G			-	1.7	V
Reverse current @ rated V_R per diode ⁽²⁾		$T_J = 25^\circ\text{C}$	I_R	-	10	μA
		$T_J = 125^\circ\text{C}$		-	400	μA
Junction capacitance per diode	HER1001G	1MHz, $V_R = 4.0\text{V}$	C_J	60	-	pF
	HER1002G			60	-	pF
	HER1003G			40	-	pF
	HER1004G			40	-	pF
Reverse recovery time	HER1005G	$I_F = 0.5\text{A}, I_R = 1.0\text{A}, I_{rr} = 0.25\text{A}$	t_{rr}	-	50	ns
	HER1006G			-	80	ns
	HER1007G					
	HER1008G					

Notes:

1. Pulse test with $PW = 0.3\text{ms}$
2. Pulse test with $PW = 30\text{ms}$

ORDERING INFORMATION		
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING
HER10xG	TO-220	50 / Tube
HER10xGH	TO-220	50 / Tube

Notes:

1. "x" defines voltage from 50V(HER1001G) to 1000V(HER1008G)
2. "H" means AEC-Q101 qualified



CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

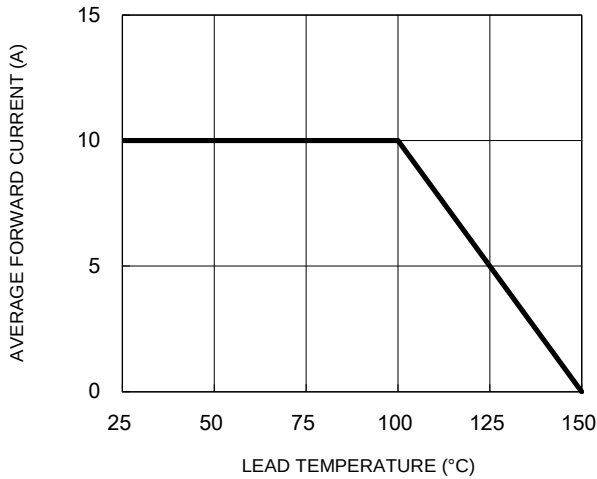


Fig.2 Typical Junction Capacitance

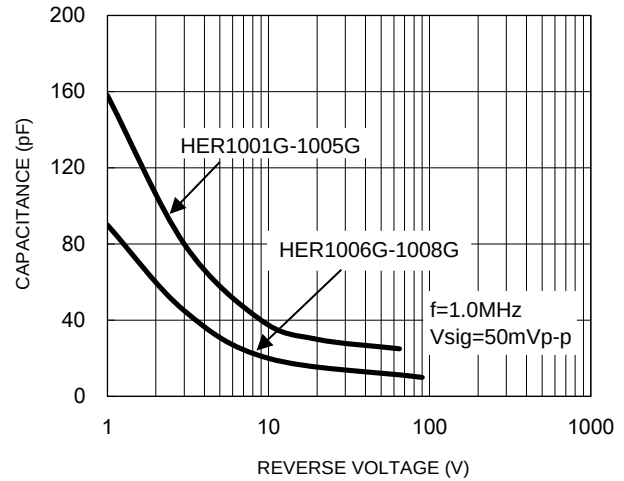


Fig.3 Typical Reverse Characteristics

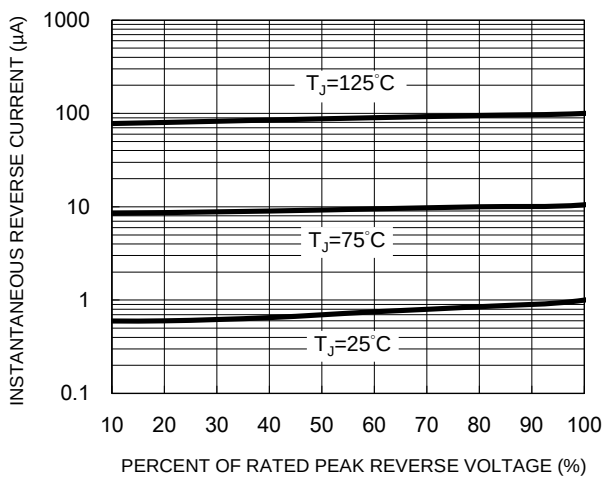


Fig.4 Typical Forward Characteristics

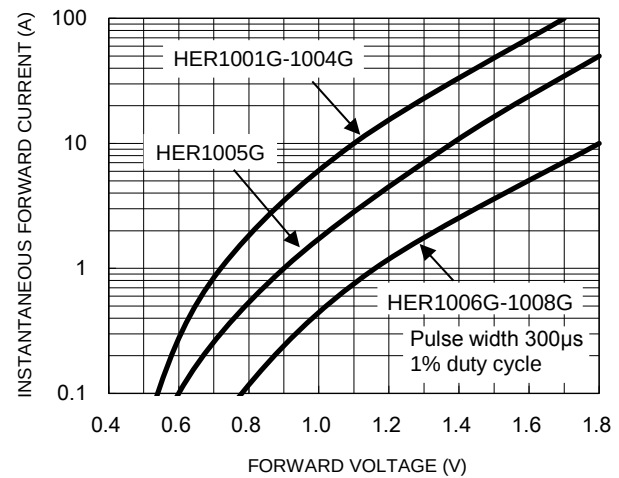


Fig.5 Maximum Non-Repetitive Forward Surge Current

